

Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. 0068-0399-0		SERIAL NO. <u>09/420,524</u> New Application	
LIST OF REFERENCES CITED BY APPLICANT				APPLICANT Masakazu KANECHIKA, et al.			
				FILING DATE Herewith		GROUP <u>2823</u>	
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES NO		
<u>JAG</u>	AO	6-163481	06/10/94	JAPAN (with English Abstract)		XX	
<u>JAG</u>	AP	9-260312	10/03/97	JAPAN (with English Abstract)		XX	
	AQ						
	AR						
	AS						
	AT						
	AU						
	AV						
OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)							
<u>JAG</u>	AW	Seigo KANEMARU, et al., "FABRICATION OF METAL-OXIDE-SEMICONDUCTOR FIELD-EFFECT-TRANSISTOR-STRUCTURED SILICON FIELD EMITTERS WITH A POLYSILICON DUAL GATE", Jpn. J. Appl. Phys., Vol. 36, Part 1, No. 12B, December 1997, pages 7736-7740					
<u>JAG</u>	AX	Yoshikazu HORI, et al., "NEW SUB-MICRON SIZE Si FIELD EMITTER ARRAYS WITH LOW OPERATION VOLTAGE", Technical Report of The Institute of Electronics Information and Communication Engineers, ED94-95, 1994-12, pages 1-8, (With English Abstract)					
	AY						
	AZ						
Examiner <u>Joanne A. Garcia</u>					Date Considered <u>July 13, 2002</u>		
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							